February 2008

# SG5851 Low-Cost Green-Mode PWM Controller for Flyback Converters

### **Features**

- Green-Mode PWM
- Supports the "Blue Angel" Standard
- Low Start-up Current: 9µA
- Low Operating Current: 3mA
- Leading-Edge Blanking
- Constant Output Power Limit
- Universal Input
- Built-in Synchronized Slope Compensation
- **Current Mode Operation**
- Cycle-by-cycle Current Limiting
- Under-Voltage Lockout (UVLO)
- Programmable PWM Frequency with Frequency Hopping
- V<sub>DD</sub> Over-Voltage Protection (Auto Restart)
- Gate Output Voltage Clamped at 17V
- Low Cost
- Few External Components Required

## **Description**

This highly integrated PWM controller provides several special enhancements designed to meet the low standby-power needs of low-power SMPS. To minimize standby power consumption, the proprietary greenmode function provides off-time modulation to linearly decrease the switching frequency under light-load conditions. This green-mode function enables the power supply to meet even the strictest power conservation requirements.

The BiCMOS fabrication process enables reducing the start-up current to 9µA and the operating current to 3mA. To further improve power conservation, a large start-up resistance can be used. Built-in synchronized slope compensation ensures the stability of peak current mode control. Proprietary internal compensation provides a constant output power limit over a universal AC input range (90V<sub>AC</sub> to 264V<sub>AC</sub>). Pulse-by-pulse current limiting ensures safe operation even during short-circuit conditions.

To protect the external power MOSFET from being damaged by supply over voltage, the output driver is clamped at 17V. SG5851 controllers, available in an SOP package, can be used to improve the performance and reduce the production cost of power supplies.

## **Applications**

- **Power Adaptors**
- Open-Frame SMPS

## **Ordering Information**

Part Number	Operating Temperature Range	Package	Packing Method	
SG5851SZ -40°C to +85°C		8-pin Small Outline Package (SOP)	Tape & Reel	
SG5851DZ	-40°C to +85°C	8-pin Dual in-line Package (DIP)	Rail	

All packages are lead free per JEDEC: J-STD-020B standard.

# **Application Diagram**

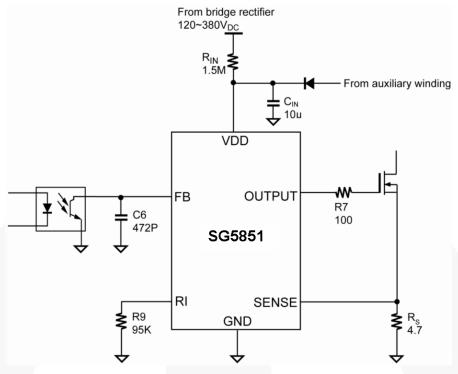


Figure 1. Typical Application

# **Block Diagram**

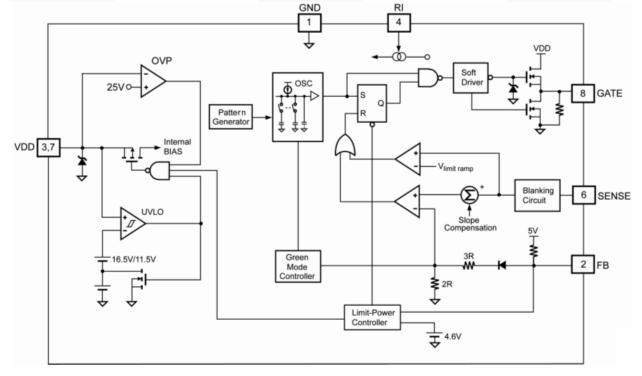


Figure 2. Function Block Diagram

# **Pin Configuration**

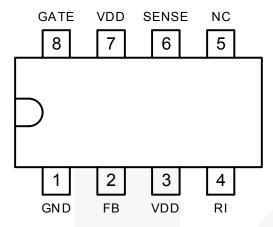


Figure 3. Pin Configuration(Top View)

# **Pin Definitions**

Pin#	Name	Description					
1	GND	ound. For ATX SMPS, it detects AC line voltage through the main transformer.					
2	FB	Feedback.					
3	VDD	Power Supply.					
4	RI	<b>Reference Setting</b> . A resistor connected from the RI pin to ground generates a constant current source used to charge an internal capacitor and determine the switching frequency. Increasing the resistance reduces the amplitude of the current source and reduces the switching frequency. A 95k $\Omega$ resistor, R <sub>I</sub> , results in a 50μA constant current I <sub>I</sub> and a 70kHz switching frequency.					
5	NC	No Connection.					
6	SENSE	<b>Current Sense</b> . This pin senses the voltage across a resistor. When the voltage reaches the internal threshold, PWM output is disabled. This activates over-current protection. This pin also provides current amplitude information for current-mode control.					
7	VDD	Power Supply.					
8	GATE	Driver Output. The totem-pole output driver for driving the power MOSFET.					

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
$V_{VDD}$	DC Supply Voltage		30	٧
$V_{FB}$	Input Voltage to FB Pin	-0.5	7.0	٧
V <sub>SENSE</sub>	Input Voltage to Sense Pin	-0.5	7.0	٧
P <sub>D</sub>	Power Dissipation		300	mW
TJ	Operating Junction Temperature		150	°C
θЈА	Thermal Resistance (Junction to Air)		141	°C/W
T <sub>STG</sub>	Storage Temperature Range	-55	150	°C
TL	Lead Temperature (Wave soldering, or IR 10 seconds)		260	°C
ESD	Electrostatic Discharge Capability, Human Body Model		3.0	KV
LOD	Electrostatic Discharge Capability, Machine Model		200	V

#### Notes:

- 1. All voltage values, except differential voltage, are given with respect to GND pin.
- 2. Stresses beyond those listed under "absolute maximum ratings "may cause permanent damage to the device.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Тур.	Max.	Unit
$T_A$	Operating Ambient Temperature	-40		+85	°C

## **Electrical Characteristics**

 $V_{DD}$  =15V,  $T_A$ = 25°C, unless noted operating specs.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>DD</sub> Section	on	-	l		I	
$V_{\text{DD-OP}}$	Continuous Operation Voltage				22	V
$V_{\text{DD-ON}}$	Turn-on Threshold Voltage		15.5	16.5	17.5	V
$V_{DD-OFF}$	Turn-off Threshold Voltage		10.5	11.5	12.5	V
I <sub>DD-ST</sub>	Start-up Current	$V_{DD}=V_{DD-ON}-0.1V$		9	15	μΑ
I <sub>DD-OP</sub>	Operating Supply Current	V <sub>DD</sub> =15V, GATE with 1nF to GND		3.0	3.5	mA
$V_{\text{DD-OVP}}$	V <sub>DD</sub> Over-voltage Protection level	Auto Restart	24	25	26	V
t <sub>D-VDDOVP</sub>	V <sub>DD</sub> Over-voltage Protection Debounce	Auto Restart		100		μs
Feedback	k Input Section					
V <sub>FB-OPEN</sub>	FB Output High Voltage		5			V
V <sub>FB-OL</sub>	FB Open-loop Trigger Level		4.3	4.6	4.9	V
t <sub>D-OLP</sub>	Delay Time of FB Pin Open-loop Protection			56		ms
$V_{FB-N}$	Green-Mode Entry FB Voltage		2.60	2.85	3.10	V
$V_{FB-G}$	Green-Mode Ending FB Voltage			2.2		V
$S_G$	Green-Mode Modulation Slope	R <sub>I</sub> =95KΩ	40	75	100	Hz/mV
Current-S	Sense Section					
Z <sub>SENSE</sub>	Input Impedance		10			ΚΩ
t <sub>PD</sub>	Delay to Output	V <sub>DD</sub> =13.5 to 22V	40	55	100	ns
V <sub>STHFL</sub>	Flat Threshold Voltage for Current Limit			1		V
V <sub>STHVA</sub>	Valley Threshold Voltage for Current Limit		0.75	0.80	0.85	V
t <sub>LEB</sub>	Leading-Edge Blanking Time		250	310	370	ns
DCY <sub>SAW</sub>	Duty Cycle of SAW Limit	Maximum Duty Cycle		45		%
Oscillator	r Section					
	Center Frequency	D-05KO	65	70	75	1/11-
Fosc	Hopping Range	- R <sub>I</sub> =95KΩ		±4.9		- KHz
t <sub>HOP</sub>	Hopping Period	R <sub>I</sub> =95KΩ		3.7		ms
F <sub>OSC-G</sub>	Green-Mode Frequency	R <sub>I</sub> =95KΩ		20		KHz
F <sub>DV</sub>	Frequency Variation vs. V <sub>DD</sub> Deviation	V <sub>DD</sub> =13.5 to 22V	0	0.02	2.00	%
F <sub>DT</sub>	Frequency Variation vs. Temperature Deviation	T <sub>A</sub> =-20 to 85°C			2	%
Output Se	ection					
$DCY_{MAX}$	Maximum Duty Cycle		70	75	80	%
$V_{GATE-L}$	Output Voltage Low	V <sub>DD</sub> =15V, I <sub>O</sub> =20mA			1.5	V
$V_{GATE-H}$	Output Voltage High	V <sub>DD</sub> =13.5V, I <sub>O</sub> =20mA	8			V
t <sub>r</sub>	Rising Time	V <sub>DD</sub> =15V, C <sub>L</sub> =1nF		200		ns
t <sub>f</sub>	Falling Time	V <sub>DD</sub> =15V, C <sub>L</sub> =1nF		55		ns
V <sub>GATE</sub> -	Output Clamp Voltage	V <sub>DD</sub> =22V	16	17	18	V

## **Functional Description**

SG5851 devices integrate many useful designs into one controller for low-power switch-mode power supplies. The following descriptions highlight some of the features of the SG5851 series.

### **Start-up Current**

The start-up current is only  $9\mu A$ , which allows a start-up resistor with a high resistance and a low-wattage to supply the start-up power for the controller. A  $1.5M\Omega$ , 0.25W, start-up resistor and a  $10\mu F/25V\ V_{DD}$  hold-up capacitor are sufficient for an AC-to-DC power adapter with a wide input range ( $90V_{AC}$  to  $264V_{AC}$ ).

## **Operating Current**

The operating current has been reduced to 3mA, which results in higher efficiency and reduces the  $V_{\text{DD}}$  hold-up capacitance requirement.

### **Green-Mode Operation**

The proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load conditions. On-time is limited to provide stronger protection against brownouts and abnormal conditions. The feedback current, which is sampled from the voltage feedback loop, is taken as the reference. Once the feedback current exceeds the threshold current, the switching frequency starts to decrease. This green-mode function dramatically reduces power consumption under light-load and zero-load conditions. Power supplies using the SG5851 can meet even the strictest regulations regarding standby power consumption.

#### **Oscillator Operation**

A resistor connected from the RI pin to ground generates a constant current source used to charge an internal capacitor. The charge time determines the internal clock speed and the switching frequency. Increasing the resistance reduces the amplitude of the input current and reduces the switching frequency. A  $95k\Omega$  resistor,  $R_{\rm I}$ , results in a  $50\mu A$  constant current,  $I_{\rm I}$ , and a 70kHz switching frequency. The relationship between  $R_{\rm I}$  and the switching frequency is:

$$f_{PWM} = \frac{6650}{R_I(k\Omega)}(kHz) \tag{1}$$

The range of the oscillation frequency is designed to be within  $50kHz \sim 100kHz$ .

### Leading-Edge Blanking

Each time the power MOSFET is switched on, a turnon spike occurs at the sense-resistor. To avoid premature termination of the switching pulse, a 320ns leading-edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current-limit comparator is disabled and it cannot switch off the gate driver.

## **Constant Output Power Limit**

When the SENSE voltage across the sense resistor,  $R_S$ , reaches the threshold voltage (~1.00V), the output GATE drive is turned off after propagation delay,  $t_{PD}$ . This propagation delay introduces an additional current proportional to  $t_{PD} \cdot V_{in}/L_p$ . The propagation delay is nearly constant regardless of the input line voltage  $V_{iN}$ . Higher input line voltages result in larger additional currents. At high input line voltages, the output power limit is higher than at low input line voltages.

To compensate for this output power limit variation across a wide AC input range, the threshold voltage is adjusted by adding a positive ramp. This ramp signal rises from 0.80V to 1.00V, then flattens out at 1.00V. A smaller threshold voltage forces the output GATE drive to terminate earlier. This reduces the total PWM turnon time and makes the output power equal to that of low line input. This proprietary internal compensation ensures a constant output power limit for a wide AC input voltage range  $(90V_{AC}$  to  $264V_{AC}$ ).

## **Under-Voltage Lockout (UVLO)**

The turn-on and turn-off thresholds are fixed internally at 16.5V and 11.5V. During start-up, the hold-up capacitor must be charged to 16.5V through the start-up resistor to enable SG5851. The hold-up capacitor continues to supply  $V_{\rm DD}$  until power can be delivered from the auxiliary winding of the main transformer.  $V_{\rm DD}$  must not drop below 11.5V during the start-up process. This UVLO hysteresis window ensures that the hold-up capacitor is adequate to supply  $V_{\rm DD}$  during start-up.

#### **Gate Output**

The SG5851 BiCMOS output stage is a fast totem-pole gate driver. Cross conduction has been avoided to minimize heat dissipation, increase efficiency, and enhance reliability. The output driver is clamped by an internal 17V Zener diode to protect power MOSFET transistors against undesired over-voltage gate signals.

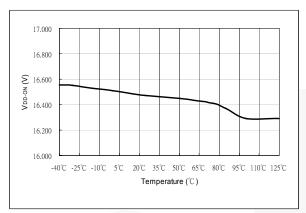
### **Built-in Slope Compensation**

The sensed voltage across the current sense resistor is used for current mode control and pulse-by-pulse current limiting. Built-in slope compensation improves stability and prevents sub-harmonic oscillations due to peak-current mode control. The SG5851 has a synchronized, positively-sloped ramp built-in at each switching cycle. The slope of the ramp is:

#### **Noise Immunity**

Noise from the current sense or the control signal can cause significant pulse-width jitter, particularly in continuous-conduction mode. While slope compensation helps alleviate these problems, further precautions should be taken. Good placement and layout practices should be followed. Avoiding long PCB traces and component leads, locating compensation and filter components near the SG5851, and increasing power MOS gate resistance improve performance.

# **Typical Performance Characteristics**



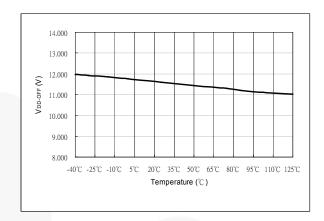
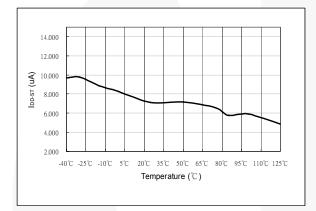


Figure 4. V<sub>DD-ON</sub> vs. T<sub>A</sub>

Figure 5. V<sub>DD-OFF</sub> vs. T<sub>A</sub> 2.000



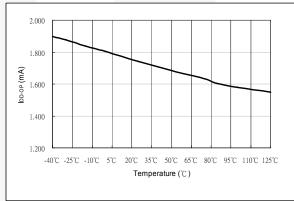
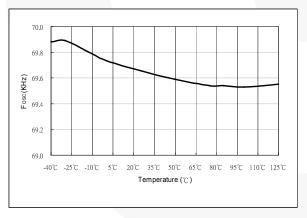


Figure 6. I<sub>DD-ST</sub> vs. T<sub>A</sub>

Figure 7. I<sub>DD-OP</sub> vs. T<sub>A</sub>



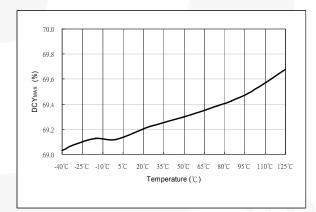
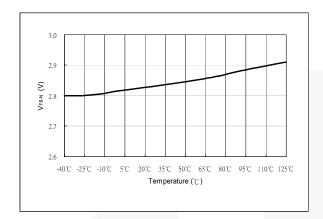


Figure 8. fosc vs. TA

Figure 9. DCY<sub>MAX</sub> vs. T<sub>A</sub>

# **Typical Performance Characteristics**



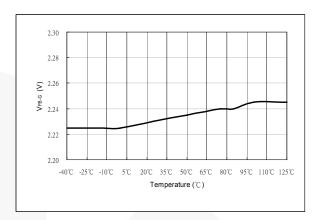


Figure 10. V<sub>FB-N</sub> vs. T<sub>A</sub>

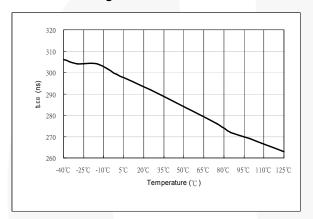


Figure 12. t<sub>LEB</sub> vs. T<sub>A</sub>

Figure 11. V<sub>FB-G</sub> vs. T<sub>A</sub>

## **Mechanical Dimensions**

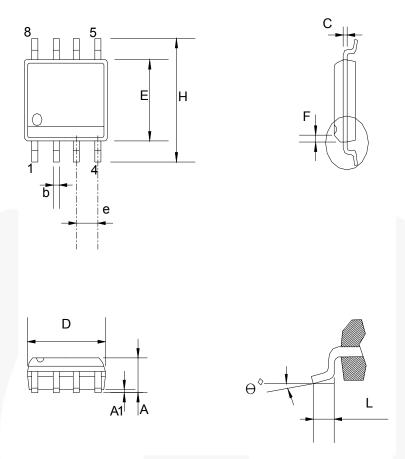


Figure 13. 8-SOIC

## **Dimensions**

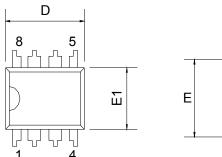
Symbol	Millimeter			Inch			
Syllibol	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	1.346		1.752	0.053		0.069	
A1	0.101		0.254	0.004		0.010	
b		0.406			0.016		
С		0.203			0.008		
D	4.648		4.978	0.183		0.196	
E	3.810		3.987	0.150	3	0.157	
е		1.270			0.050		
F		0.381X45°			0.015X45°		
Н	5.791		6.197	0.228		0.244	
L	0.406		1.270	0.016		0.050	
θ°	0°		8°	0°		8°	

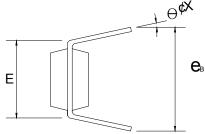
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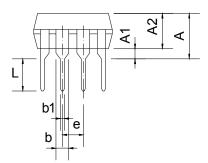


Figure 14. 8-DIPIC

### **Dimensions**

Symbol	Millimeter			Inch			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			5.334			0.210	
A1	0.381			0.015			
A2	3.175	3.302	3.429	0.125	0.130	0.135	
b		1.524			0.060		
b1		0.457			0.018		
D	9.017	9.271	10.160	0.355	0.365	0.400	
Е		7.620			0.300	7	
E1	6.223	6.350	6.477	0.245	0.250	0.255	
е		2.540			0.100	1/2	
L	2.921	3.302	3.810	0.115	0.130	0.150	
ев	8.509	9.017	9.525	0.335	0.355	0.375	
θ°	0°	7°	15°	0°	7°	15°	

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